#### **PRELIMINARY**

Notice: This is not a final specification Some parametric are subject to change.

FOR HIGH CURRENT DRIVE APPLICATION SILICON PNP EPITAXIAL TYPE

## **DESCRIPTION**

INA6001AC1 is a silicon PNP epitaxial type transistor. It is designed with high collector current and small  $V_{\text{CE(sat)}}$ .

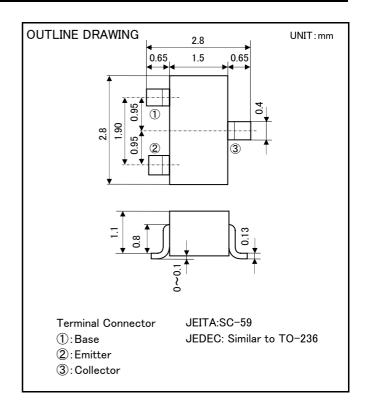
## **FEATURE**

- •Super mini package for easy mounting
- •High collector current(I<sub>C</sub>=-1A)
- •Low collector saturation voltage

$$(V_{CE(sat)} < -0.5V_{max}; I_{C} = -500 mA, I_{B} = -50 mA)$$

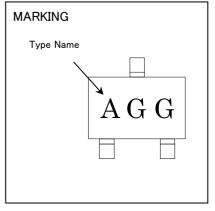
## **APPLICATION**

For switching, Small type motor drive



## MAXIMUM RATING (Ta=25°C)

SYMBOL	PARAMETER RATING		UNIT
V <sub>CEO</sub>	Collector to Emitter voltage	-100	>
V <sub>CBO</sub>	Collector to Base voltage	-120	>
$V_{EBO}$	Emitter to Base voltage	-6	٧
I <sub>c</sub>	Collector current	-1	Α
P <sub>c</sub>	Collector dissipation(Ta=25°C)	200	mW
$T_{j}$	Junction temperature	+150	လူ
$T_{stg}$	Storage temperature $-55 \sim +150$		°C



#### ELECTRICAL CHARACTERISTICS (Ta=25°C)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
STMBOL		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$	C to E break down voltage	I <sub>C</sub> =-10mA, I <sub>B</sub> =0mA	-100	_	_	V
$V_{(BR)CBO}$	C to B break down voltage	$I_{c}=-100 \mu A, I_{E}=0mA$	-120	_	_	V
$V_{(BR)EBO}$	E to B break down voltage	$I_E=-100 \mu A, I_C=0mA$	-6	_	-	V
I <sub>CBO</sub>	Collector cut off current	$V_{CB}$ =-120V, I <sub>E</sub> =0mA	_	_	-0.5	μΑ
I <sub>EBO</sub>	Emitter cut off current	$V_{EB}$ =-6V, I $_{C}$ =0mA	_	_	-0.5	μΑ
h <sub>FE1</sub>	DC forward current gain1	V <sub>CE</sub> =-2V, I <sub>C</sub> =-150mA	140	_	330	_
h <sub>FE2</sub>	DC forward current gain2	$V_{CE}$ =-5V, I $_{C}$ =-1A	40	_	-	_
V <sub>CE(sat)</sub>	C to E saturation voltage	I <sub>C</sub> =-500mA, I <sub>B</sub> =-50mA	_	_	-0.5	V
$V_{BE(sat)}$	B to E saturation voltage	I <sub>C</sub> =-500mA, I <sub>B</sub> =-50mA	_	_	-1.1	V
f <sub>T</sub>	Gain bandwidth product	V <sub>CE</sub> =-5V, I <sub>E</sub> =50mA, f=100MHz	100	_	_	MHz
Cob	Collector output capacitance	V <sub>CB</sub> =-10V, f=1MHz	_	-	10	pF



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